

# OPTIMIZATION OF A HIGH EFFICIENCY FEL AMPLIFIER

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## Abstract

The problem of an efficiency increase of an FEL amplifier is now of great practical importance. Technique of undulator tapering in the post-saturation regime is used at the existing x-ray FELs LCLS and SACLA, and is planned for use at the European XFEL, Swiss FEL, and PAL XFEL. There are also discussions on the future of high peak and average power FELs for scientific and industrial applications. In this paper we perform detailed analysis of the tapering strategies for high power seeded FEL amplifiers. Application of similarity techniques allows us to derive universal law of the undulator tapering.

## INTRODUCTION

Efficiency of FEL amplifier with untapered undulator is defined by the value of the FEL parameter  $\rho$ . Application of the undulator tapering [1] allows to increase conversion efficiency to rather high values. In the framework of the one-dimensional theory the status of the problem of tapering has been settled, and it is generally accepted that optimum law of the undulator tapering is quadratic with the linear correction for optimization of the particle's capture in the decelerating potential [2–7]. Similar physical situation occurs in the FEL amplifier with waveguide with small waveguide parameter. In this case radiation is confined with the waveguide. Physical parameters of FEL amplifiers operating in infrared, visible, and x-ray wavelength range are such that these devices are described in the framework of three dimensional theory with an “open” electron beam, i.e. physical case of pure diffraction in a free space. In this case diffraction of the radiation is essential physical effect influencing optimization of the tapering process. Discussions and studies on optimum law of the undulator tapering in 3D case are in the progress for more than 20 years. Our previous studies were mainly driven by occasional calculations of perspective FEL systems for high power scientific (for instance, FEL based  $\gamma\gamma$  - collider ) and industrial applications (for instance, for isotope separation, and lithography [8–10]). New wave of interest to the undulator tapering came with x-ray free electron lasers. It is used now not only as demonstration tool [11], but as a routine tool at operating x-ray FEL facilities LCLS and SACLA.

During an intermediate physical discussion on the subject of tapering we pointed out that asymptotical law of the undulator tapering for FEL amplifier with “open” beam should be linear in terms of the detuning parameter [7]. The origin for this statement is that radiation power of the bunched electron beam grows linearly with the undulator length for very long undulator. However, the problem of optimum matching of the electron beam into the regime of coherent deceleration is still open. Practical calculations of specific systems yielded in several empirical laws using dif-

ferent polynomial dependencies, application of tricks with detuning jumps, etc (see [12, 13] and references therein).

In this paper we perform global analysis of the parameter space of seeded FEL amplifier and derive universal law of the undulator tapering defined by the only diffraction parameter.

## BASIC RELATIONS

We consider axisymmetric model of the electron beam. It is assumed that transverse distribution function of the electron beam is Gaussian, so rms transverse size of matched beam is  $\sigma = \sqrt{\epsilon\beta}$ , where  $\epsilon = \epsilon_n/\gamma$  is rms beam emittance,  $\gamma$  is relativistic factor, and  $\beta$  is focusing beta-function. In the following we consider rectified case of the “cold” electron beam and neglect space charge effects. Under this assumptions the FEL amplifier is described by the diffraction parameter  $B$  [7], and detuning parameter  $\hat{C}$ :

$$B = 2\Gamma\sigma^2\omega/c, \quad \hat{C} = C/\Gamma, \quad (1)$$

where  $\Gamma = [I\omega^2\theta_s^2 A_{JJ}^2 / (I_A c^2 \gamma_z^2 \gamma)]^{1/2}$  is the gain parameter,  $C = 2\pi/\lambda_w - \omega/(2c\gamma_z^2)$  is the detuning of the electron with the nominal energy  $\mathcal{E}_0$ . In the following electron energy is normalized as  $\hat{P} = (E - E_0)/(\rho E_0)$ , where  $\rho = c\gamma_z^2\Gamma/\omega$  is the efficiency parameter<sup>1</sup>. The following notations are used here:  $I$  is the beam current,  $\omega = 2\pi c/\lambda$  is the frequency of the electromagnetic wave,  $\theta_s = K_{rms}/\gamma$ ,  $K_{rms}$  is the rms undulator parameter,  $\gamma_z^{-2} = \gamma^{-2} + \theta_s^2$ ,  $k_w = 2\pi/\lambda_w$  is the undulator wavenumber,  $I_A = 17$  kA is the Alfvén current,  $A_{JJ} = 1$  for helical undulator and  $A_{JJ} = J_0(K_{rms}^2/2(1 + K_{rms}^2)) - J_1(K_{rms}^2/2(1 + K_{rms}^2))$  for planar undulator. Here  $J_0$  and  $J_1$  are the Bessel functions of the first kind.

Equations, describing motion of the particles in the ponderomotive potential well of electromagnetic wave and undulator get simple form when written down in normalized form (see, e.g. [7]):

$$\frac{d\Psi}{d\hat{z}} = \hat{C} + \hat{P}, \quad \frac{d\hat{P}}{d\hat{z}} = U \cos(\phi_U + \Psi), \quad (2)$$

where  $\hat{z} = \Gamma z$ , and  $U$  and  $\phi_U$  are amplitude and phase of effective potential. Energy change of electrons is small in the exponential stage of amplification,  $\hat{P} \ll 1$ , and process of electron bunching in phase  $\Psi$  lasts for long distance,  $\hat{z} \gg 1$ . Situation changes drastically when electron energy change  $\hat{P}$  approaches to the unity. The change of phase on the scale of  $\Delta\hat{z} \approx 1$  becomes to be fast, particles start to slip in phase  $\Psi$  which leads to the debunching of the electron beam modulation, and growth of the radiation power is saturated. operation. Undulator tapering [1], i.e. adjustment of the detuning

<sup>1</sup> Note that it differs from 1-D definition by the factor  $B^{1/3}$  [7].

according to the energy loss of electrons,  $\hat{C}(\hat{z}) = -\hat{P}(\hat{z})$ , allows to keep synchronism of electrons with electromagnetic wave and increase output power.

### Radiation of Modulated Electron Beam

FEL radiation is coherent radiation of the electron beam which is modulated at the resonance wavelength during amplification process. It is reasonable here to remember properties of the radiation of the modulated electron beam. Radiation power of modulated beam in helical undulator is given by [14]:

$$P = \frac{\pi\theta_s^2\omega I_0^2 a_{in}^2 z}{4\pi c^2} \left[ \arctan\left(\frac{1}{2N}\right) + N \ln\left(\frac{4N^2}{4N^2+1}\right) \right], \quad (3)$$

where  $a_{in}$  is amplitude of modulation of the electron beam current ( $I(z,t) = I_0[1 + a_{in} \cos \omega(z/v_z - t)]$ ), and  $N = k\sigma^2/z$  is Fresnel number. We note here that expression (3) is a crucial element for understanding the optimum law of the undulator tapering. Indeed, in the deep tapering regime some fraction of the particles is trapped in the regime of coherent deceleration. Thus, beam modulation is fixed, and asymptotically radiation power should be described by (3). One can easily find that both asymptotes of undulator tapering discussed in the introductory section: 1D model of (wide electron beam), and thin beam asymptote are well described by this expression. Asymptote of wide electron beam corresponds to large values of Fresnel number  $N$ , and it follows from (3) that radiation power scales as  $P \propto z^2$ . Asymptote of thin electron beam corresponds to small values of the Fresnel Number  $N$ , and radiation power becomes linearly proportional to the undulator length,  $P \propto z$ . Undulator tapering should adjust detuning according to the energy loss by electrons, and we find that tapering law should be quadratic for the case of wide electron beam,  $C \propto -P \propto z^2$ , and linear - for the case of thin electron beam,  $C \propto -P \propto z$ .

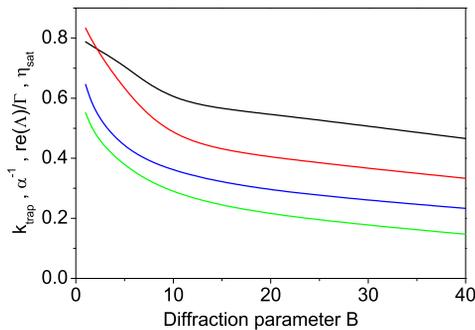


Figure 1: Universal characteristics of FEL amplifier. Color codes are: black - trapping efficiency  $K_{trap}$  for globally optimized undulator; red - fitting coefficient of global optimization  $\alpha_{tap}^{-1}$ ; blue - FEL field gain  $\text{Re } \Lambda/\Gamma$ ; green - FEL efficiency in the saturation,  $\eta_{sat} = P_{sat}/(\rho P_b)$ .

### GLOBAL OPTIMIZATION

We start with global optimization of the parameter space. Simulations have been performed with three-dimensional, time-dependent FEL simulation code [15]. In the framework of the accepted model (cold electron beam) both, field gain  $\text{Re } \Lambda/\Gamma$  and efficiency in the saturation,  $\eta_{sat} = P_{sat}/(\rho P_b)$  of the FEL amplifier tuned to exact resonance are defined by the only diffraction parameter  $B$  (see Fig.1). Operation of the FEL amplifier before saturation is also defined by the diffraction parameter  $B$ . One can clearly observe this from Fig. 2. Here longitudinal coordinate is normalized to the gain length  $L_g = 1/(\text{Re } \Lambda/\Gamma)$ , and radiation power is normalized to the saturation power. When amplification process enters nonlinear stage, output power is function of two parameters, diffraction parameter and reduced undulator length.

Now we come to the problem of efficiency increase with undulator tapering. First, we solve this problem using approach of straightforward global optimization. The function of optimization is to find maximum of the output power at the undulator length exceeding ten field gain lengths. We divide undulator into many pieces and change detuning of all pieces independently. We apply adiabatic (smooth) tapering, i.e. we prevent jumps of the detuning on the boundary of the sections. Number of sections is controlled to be large enough to provide the result which is independent on the number of sections. Then we choose tapering law  $C(B, z)$  corresponding to the maximum power at the exit of the whole undulator. This global optimization procedure has been performed in the practically important range of diffraction parameters from  $B = 1$  to  $B = 40$ . Results of this global optimization are summarized in Fig. 3. Ratio of the normalized power to the normalized detuning gives us the value of trapping efficiency of electrons into the regime of coherent deceleration,  $K_{trap} = \hat{P}/\hat{C}$ . This universal function of diffraction parameter  $B$  is plotted on Fig: 1. We find that optimum trapping factor approaches values of 80% for  $B = 1$ , and falls down to 45% for  $B = 40$ . It is interesting to notice that for  $B \gtrsim 5$  it scales roughly as  $B^{-1/3}$ , similar

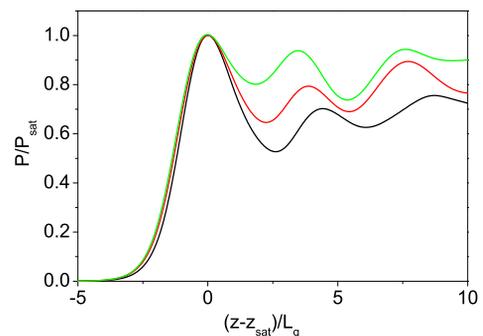


Figure 2: Evolution of the radiation power along the undulator (untapered case). Color codes: black, red, green curves correspond to the value of diffraction parameter  $B = 1, 10$ , and 40.

to other FEL characteristics like FEL gain and saturation efficiency.

It comes from global optimization that in the whole parameter range undulator tapering starts from the value of  $\Delta z \approx 2L_g$  before saturation. This is not surprising if we look on Fig. 2. Optimum undulator tapering should compensate loss of the electron energy which in fact follows identical parametric dependence on the gain  $L_g$  for all values of diffraction parameter. Next observations come from the analysis of the beam modulation. The first observation is that the beam modulation at the initial stage of the non-linear regime follows similar behavior for all diffraction parameters (see Fig. 4). This gives a hint that initial capture of the particles is performed in a similar way in the whole parameter range. The second observation is that the beam modulation after trapping of the electrons to the coherent deceleration process remains constant along the undulator, and it is universal function of the diffraction parameter  $B$  (see Fig. 4). This gives us the main hint which we discussed in the previous section. I.e., excluding trapping transition stage, we deal with radiation of the modulated electron beam (3). Main essence of our study is to apply para-

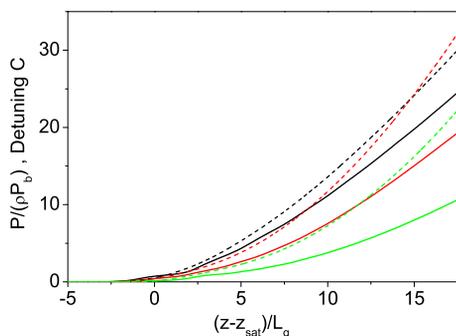


Figure 3: Evolution along the undulator of the output power (solid curves) and detuning (dashed curves) for FEL amplifier with global optimization of the undulator tapering. Color codes: black, red, green curves correspond to the value of diffraction parameter  $B = 1, 10, \text{ and } 40$ .

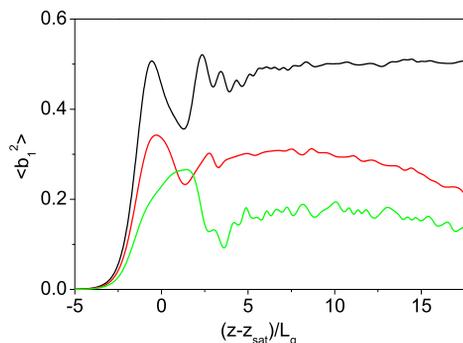


Figure 4: Evolution along the undulator of the squared value of the beam bunching for FEL amplifier with global undulator tapering. Color codes: black, red, green curves correspond to the value of diffraction parameter  $B = 1, 10, \text{ and } 40$ .

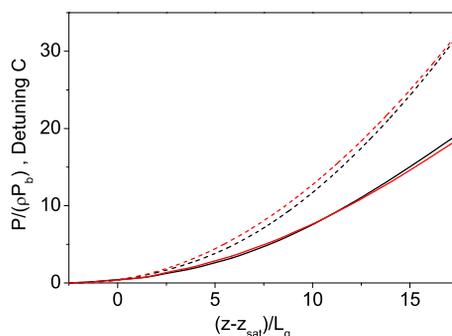


Figure 5: Evolution along the undulator of the output power (solid curves) and detuning (dashed curves) Color codes: black - FEL with global optimization of undulator tapering, red - fit with formula (4). Here the value of diffraction parameter is  $B = 10$ .

metrical dependence like (3) to fit optimum detuning pattern in Fig. 3 such that condition of optimum tapering is preserved:

$$\hat{C} = \alpha_{tap} (\hat{z} - \hat{z}_0) \left[ \arctan \left( \frac{1}{2N} \right) + N \ln \left( \frac{4N^2}{4N^2 + 1} \right) \right], \quad (4)$$

with Fresnel number  $N$  fitted by  $N = \beta_{tap} / (\hat{z} - \hat{z}_0)$ . Thus, we try to fit optimum detuning with three parameters:  $z_0$ ,  $\alpha_{tap}$  and  $\beta_{tap}$ . Here undulator length is normalized to the gain parameter,  $\hat{z} = \Gamma z$ . One parameter of this fit, start of the undulator tapering  $z_0$  is firmly fixed by the global optimization procedure,  $z_0 = z_{sat} - 2L_g$ . Another parameter of the problem,  $\beta_{tap}$ , is rather well approximated with the linear dependency on diffraction parameter,  $\beta_{tap} = 10 \times B$ . Remaining parameter,  $\alpha_{tap}$  is plotted in Fig. 1. It is slow function of the diffraction parameter  $B$ , and scales approximately to  $B^{1/3}$  as all other important FEL parameters presented in Fig. 1. Thus, application of similarity techniques gives us an elegant way for general parametrical fit of such complicated phenomena as optimum undulator tapering. Actually, accuracy of this fit is pretty good giving the results for optimum detuning which are close to the global optimum. We illustrate with Fig. 5 tapering law (4) for specific value of the diffraction parameter  $B = 10$ . Curves in black color are normalized power and detuning derived from global optimization. Red dashed curve is detuning  $\hat{C}$  given by (4) with  $\alpha_{tap} = 2.2$  (see Fig. 1, and  $\beta_{tap} = 100$  (according to relation  $\beta_{tap} = 10 \times B$ ). The solid curve in red color is normalized FEL efficiency simulated using detuning (4). We see good agreement of the fit with global optimization. The same situation occurs in the whole range of traced values of diffraction parameter  $B$ . Such a good agreement is not surprising since fitting is based on very clean parametric dependencies, and numerical simulations just provided relevant numerical factors.

We finish our paper with illustration of the trapping process. Trapping efficiency  $K_{trap} = \hat{P} / \hat{C}$  is plotted in Fig. 1. Trapping efficiency falls down with diffraction parameter  $B$ .

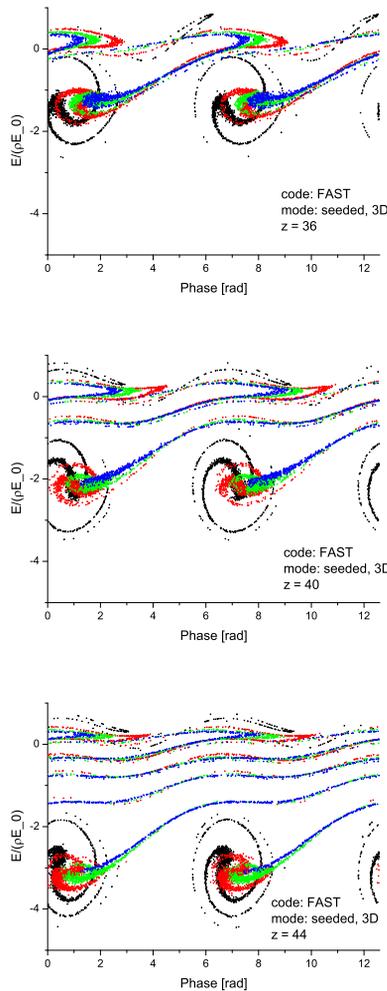


Figure 6: Phase space distribution of electrons at different stages of trapping process. Color codes correspond to different location of the particles in the beam (black - core of the beam, blue - edge of the beam). Here diffraction parameter is  $B = 10$ . Top, middle, and bottom plots correspond to  $(z - z_{sat})/L_g = 2.5, 3.9$  and  $5.3$ , respectively (see Fig. 5).

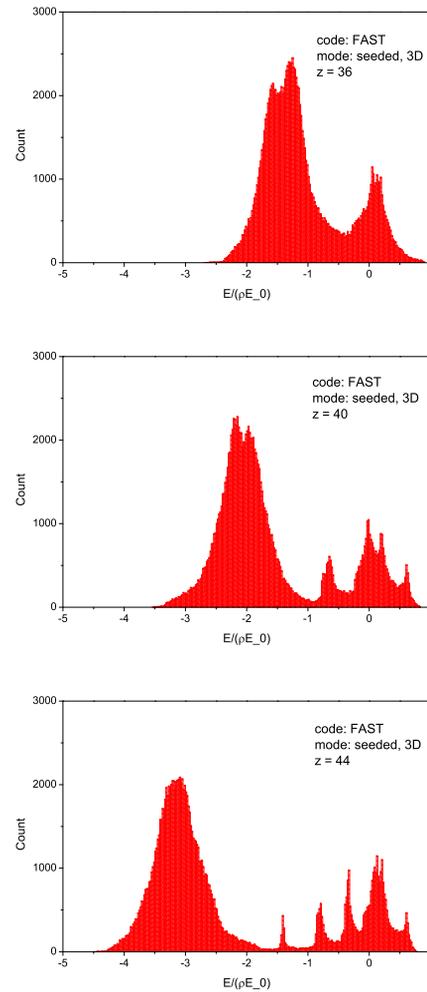


Figure 7: Population of electrons in energy at different stages of trapping process. Color codes correspond to different location of the particles in the beam (black - core of the beam, blue - edge of the beam). Here diffraction parameter is  $B = 10$ . Top, middle, and bottom plots correspond to  $(z - z_{sat})/L_g = 2.5, 3.9$  and  $5.3$ , respectively (see Fig. 5).

This is natural consequence of diffraction effects discussed earlier (see, e.g. [7], Chap. 4). For small value of the diffraction parameter  $B$  gradient of the field of the beam radiation mode across the electron bunch is smaller than for large values of diffraction parameter. In the latter case we obtain situation when electrons located in the core of the electron beam are already fully bunched while electrons on the edge of the beam are not bunched yet. As a result, number of electrons with similar positions on the energy-phase plane falls down with the growth of the diffraction parameter, as well as trapping efficiency into the regime of coherent deceleration. The trapping process is illustrated with phase space plots presented on Fig. 6 for the value of diffraction parameter  $B = 10$ . Top, middle, and bottom plots correspond to the points of  $(z - z_{sat})/L_g = 2.5, 3.9$  and  $5.3$  on Fig. 3. Different color codes (black to blue) correspond to differ-

ent locations of the particles across the beam (core to edge. We see that particles in the core of bunch (black points) are trapped most effectively. Nearly all particles located in the edge of the electron beam (blue points) leave stability region very soon. Trapping process lasts for several field gain length when trapped particles become to be isolated in the trapped energy band for which undulator tapering is optimized further. For specific value of the diffraction parameter  $B = 10$  it is not finished even at three field gain lengths after saturation, and non-trapped particles continue to populate low energy tail of the energy distribution (see Fig. 7). Recently we have been invited to the discussion on the details of trapped particles distribution in the phase space observed experimentally at LCLS [16]. Graphs presented in Figs. 6 and 7 give a hint on the origin of energy bands which are formed by non-trapped particles. This is consequence

of nonlinear dynamics of electrons leaving the region of stability. Actually, similar effect can be seen in the early 1D studies [5, 6].

## DISCUSSION

In this paper we derived general law for optimum undulator tapering in the presence of diffraction effects. Purified case of “cold” electron has been considered. This allowed us to isolate diffraction effects in the most clear form. It has been found that universal function of the undulator tapering depends on the only diffraction parameter. Tapering law is described with simple analytical expression with two fitting coefficients. Extension of this approach to practical life (including energy spread and emittance) is pretty much straightforward and will result in corrections to the fitting coefficients without changing general law given by (4). The same law is evidently applicable to SASE FEL as well with relevant correction of fitting coefficients.

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